

### Features

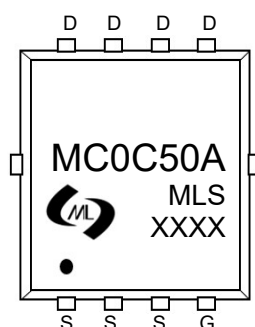
- High density cell design for ultra low  $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

### Application

- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

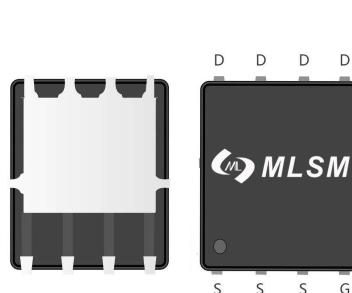
### Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX   | $I_D$ MAX |
|----------|--------------------|-----------|
| 20V      | 10m $\Omega$ @10V  | 50A       |
|          | 13m $\Omega$ @4.5V |           |

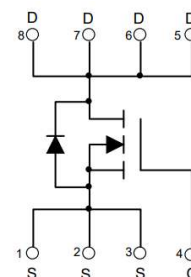


MC0C50A: Device code  
XXXX : Code

Marking and pin assignment



PDFN5X6-8L view



Schematic diagram



Halogen-Free

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

### Common Ratings ( $T_C=25^\circ\text{C}$ Unless Otherwise Noted)

|                  |                                  |         |            |    |
|------------------|----------------------------------|---------|------------|----|
| V <sub>DS</sub>  | Drain-Source Breakdown Voltage   |         | 20         | V  |
| V <sub>GS</sub>  | Gate-Source Voltage              |         | ±12        | V  |
| T <sub>J</sub>   | Maximum Junction Temperature     |         | 150        | °C |
| T <sub>STG</sub> | Storage Temperature Range        |         | -50 to 155 | °C |
| I <sub>S</sub>   | Diode Continuous Forward Current | Tc=25°C | 50         | A  |

### Mounted on Large Heat Sink

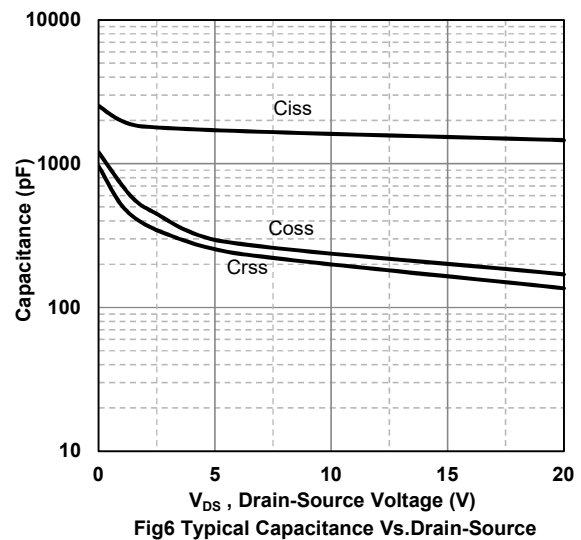
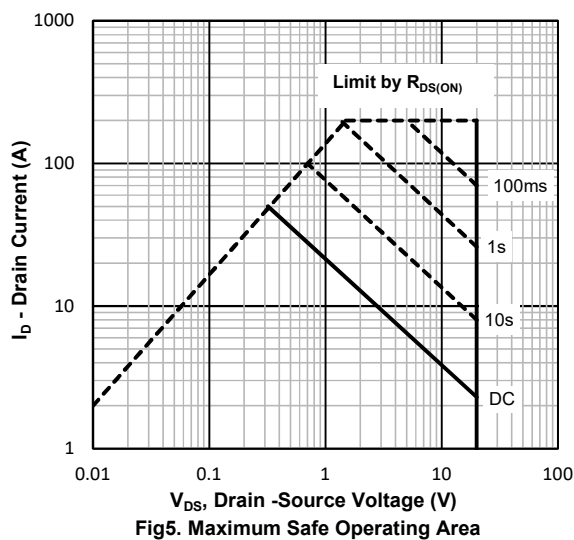
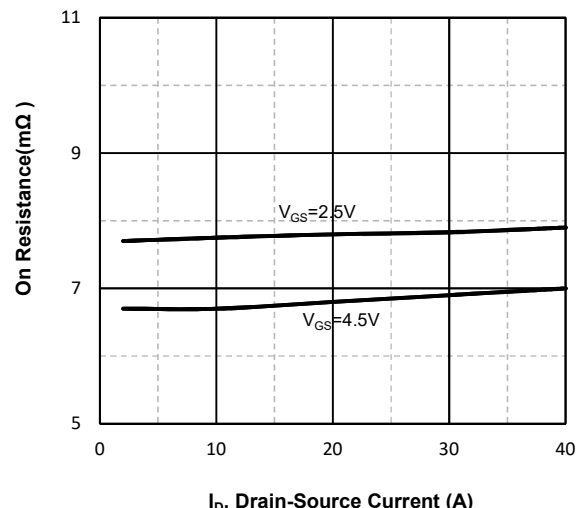
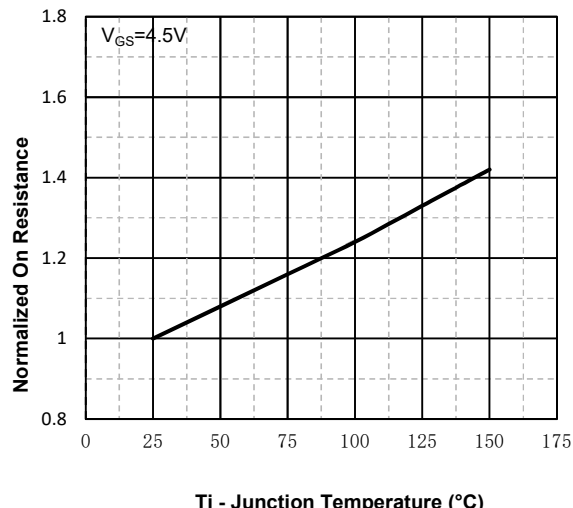
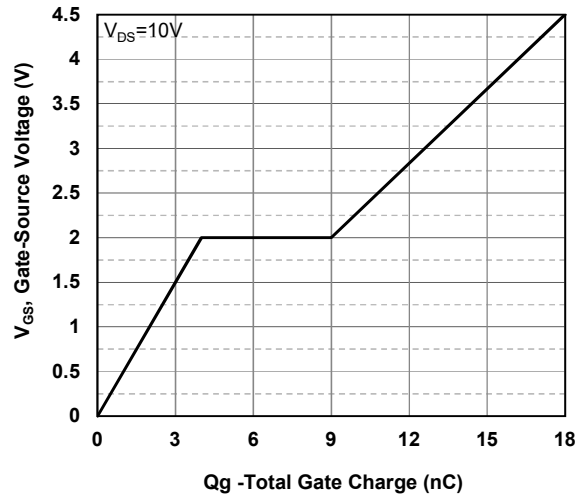
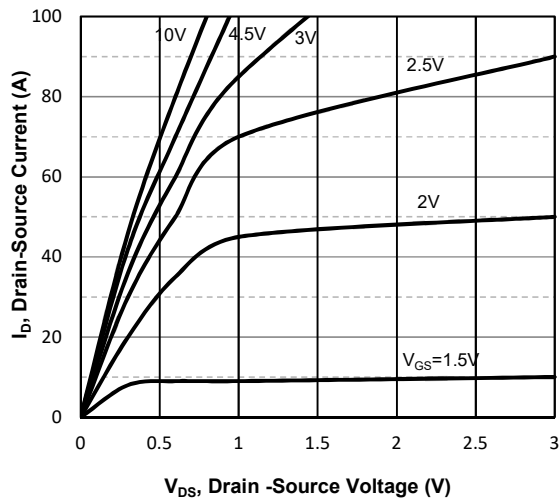
|          |                               |                        |       |    |
|----------|-------------------------------|------------------------|-------|----|
| $I_{DM}$ | Pulse Drain Current Tested    | $T_C=25^\circ\text{C}$ | 200   | A  |
| $I_D$    | Continuous Drain Current      | $T_C=25^\circ\text{C}$ | 50    | A  |
| $P_D$    | Maximum Power Dissipation     | $T_C=25^\circ\text{C}$ | 31    | W  |
| $E_{AS}$ | Single pulse avalanche energy |                        | 11.25 | mJ |

### Ordering Information (Example)

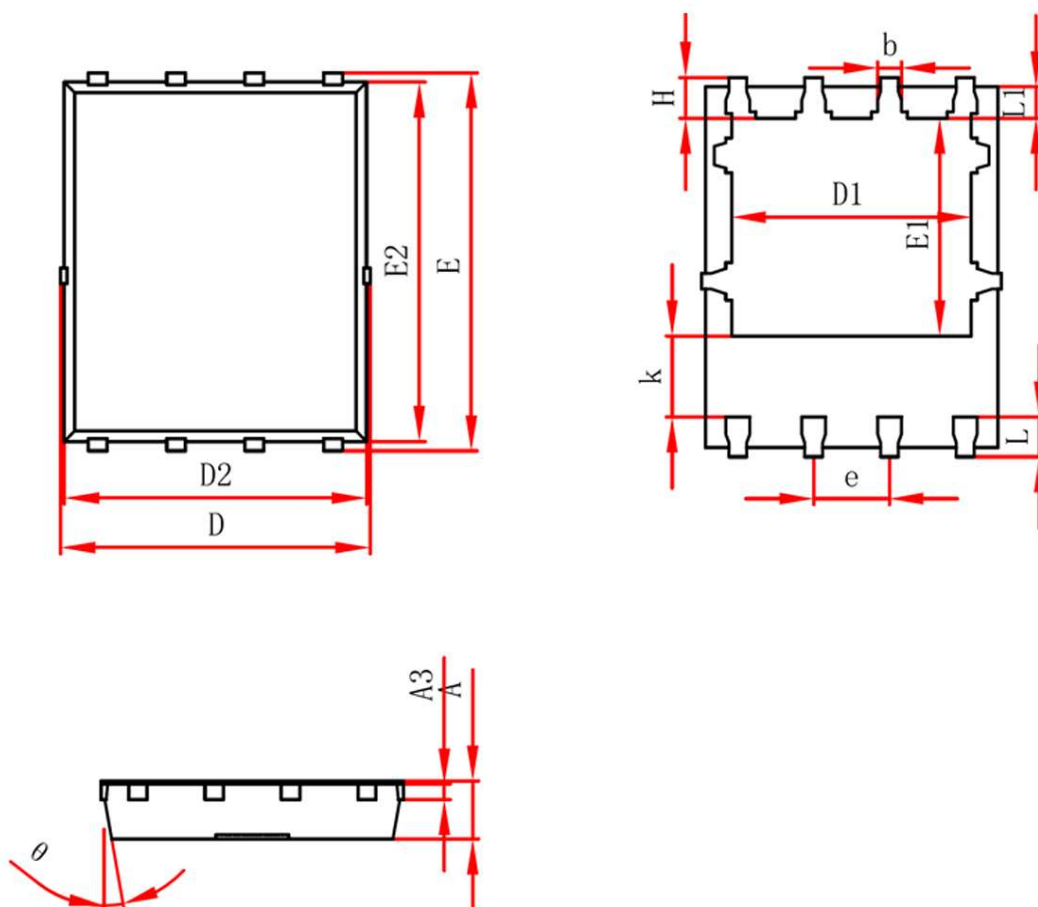
| Type    | Package    | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|---------|------------|---------|----------------------|-------------------------|----------------------------|---------------|
| MC0C50A | PDFN5X6-8L | MC0C50A | 5,000                | 10,000                  | 70,000                     | 13"reel       |

| Electrical Characteristics (TJ=25°C unless otherwise noted)              |                                  |                                                                                      |      |      |      |      |
|--------------------------------------------------------------------------|----------------------------------|--------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                                   | Parameter                        | Condition                                                                            | Min  | Typ  | Max  | Unit |
| Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)  |                                  |                                                                                      |      |      |      |      |
| BV <sub>(BR)DSS</sub>                                                    | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                           | 20   | --   | --   | V    |
| I <sub>DSS</sub>                                                         | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V                                            | --   | --   | 1    | μA   |
| I <sub>GSS</sub>                                                         | Gate-Body Leakage Current        | V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V                                           | --   | --   | ±100 | nA   |
| V <sub>GS(th)</sub>                                                      | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                             | 0.45 | 0.75 | 1.2  | V    |
| R <sub>DS(on)</sub>                                                      | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =20A                                            | --   | 6.8  | 10   | mΩ   |
|                                                                          |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =18A                                           | --   | 8    | 13   | mΩ   |
|                                                                          |                                  | V <sub>GS</sub> =2.5V, I <sub>D</sub> =5A                                            | --   | 12   | 19   | mΩ   |
| Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated) |                                  |                                                                                      |      |      |      |      |
| C <sub>ISS</sub>                                                         | Input Capacitance                | V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz                                    | --   | 1613 | --   | pF   |
| C <sub>OSS</sub>                                                         | Output Capacitance               |                                                                                      | --   | 228  | --   | pF   |
| C <sub>RSS</sub>                                                         | Reverse Transfer Capacitance     |                                                                                      | --   | 200  | --   | pF   |
| Switching Characteristics                                                |                                  |                                                                                      |      |      |      |      |
| Q <sub>g</sub>                                                           | Total Gate Charge                | V <sub>DS</sub> =10V, I <sub>D</sub> =25A, V <sub>GS</sub> =4.5V                     | --   | 18   | --   | nC   |
| Q <sub>gs</sub>                                                          | Gate Source Charge               |                                                                                      | --   | 3.5  | --   | nC   |
| Q <sub>gd</sub>                                                          | Gate Drain Charge                |                                                                                      | --   | 5.5  | --   | nC   |
| t <sub>d(on)</sub>                                                       | Turn-on Delay Time               | V <sub>DD</sub> =10V, I <sub>D</sub> =25A, V <sub>GS</sub> =4.5V, R <sub>G</sub> =3Ω | --   | 9    | --   | nS   |
| t <sub>r</sub>                                                           | Turn-on Rise Time                |                                                                                      | --   | 19   | --   | nS   |
| t <sub>d(off)</sub>                                                      | Turn-Off Delay Time              |                                                                                      | --   | 38   | --   | nS   |
| t <sub>f</sub>                                                           | Turn-Off Fall Time               |                                                                                      | --   | 24   | --   | nS   |
| Source- Drain Diode Characteristics                                      |                                  |                                                                                      |      |      |      |      |
| V <sub>SD</sub>                                                          | Forward on voltage               | Tj=25°C, Is=25A                                                                      | --   | --   | 1.2  | V    |

## Typical Operating Characteristics



PDFN5X6-8L Package information



| Symbol | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 0.950                         | 1.050 | 0.035                | 0.039 |
| A3     | 0.254REF.                     |       | 0.010REF.            |       |
| D      | 4.950                         | 5.050 | 0.196                | 0.200 |
| E      | 5.950                         | 6.050 | 0.235                | 0.239 |
| D1     | 4.026                         | 4.126 | 0.159                | 0.163 |
| E1     | 3.510                         | 3.610 | 0.139                | 0.143 |
| D2     | 4.850                         | 4.950 | 0.192                | 0.196 |
| E2     | 5.700                         | 5.800 | 0.225                | 0.229 |
| k      | 1.190                         | 1.390 | 0.047                | 0.055 |
| b      | 0.300                         | 0.400 | 0.012                | 0.016 |
| e      | 1.270TYP.                     |       | 0.050TYP.            |       |
| L      | 0.559                         | 0.711 | 0.022                | 0.028 |
| L1     | 0.424                         | 0.576 | 0.017                | 0.023 |
| H      | 0.574                         | 0.726 | 0.023                | 0.029 |
| θ      | 10°                           | 12°   | 10°                  | 12°   |